IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In repatent application of

Hayashi et al.

Serial No. (not assigned)

Examiner (not assigned)

Filed concurrently herewith

Art Unit (not assigned)

For MAGNETORESISTIVE EFFECT SENSOR, METHOD FOR MANUFACTURING A MAGNETORESISTIVE EFFECT SENSOR, MAGNETORESISTIVE DETECTION SYSTEM, AND MAGNETORESISTIVE RECORDING SYSTEM

Assistant Commissioner of Patents Washington, D.C. 20231

PRELIMINARY AMENDMENT

Dear Sir:

Prior to calculation of the filing fee, Applicant wishes to amend the application as follows:

In the Claims:

Please amend claim 3 as follows (a marked up version of claim 3 being appended hereto):

3. A magnetoresistive effect sensor according to claim 1, wherein said lower shield is made of a material of CoZrTa and CoZrTaCr alloy, as a base.

REMARKS

The amendment avoids multiple dependent claim language and does not introduce new matter.

 Please proceed to examination on the merits.

Respectfully submitted,

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Marked-Up Version of the Claims

Claim 3 (once amended). A magnetoresistive effect sensor according to claim 1 [or claim 2], wherein said lower sheild is made of a material of CoZrTa and CoZrTaCr alloy, as a base.